

# DM74S289

## 64-Bit (16 x 4) Open-Collector RAM TRI-STATE® RAM

### General Description

These 64-bit active-element memories are monolithic Schottky-clamped transistor-transistor logic (TTL) arrays organized as 16 words of 4 bits each. They are fully decoded and feature a chip-enable input to simplify decoding required to achieve the desired system organization. The memories feature PNP input transistors that reduce the low level input current requirement to a maximum of  $-25$  mA, only one-eighth that of a DM74S standard load factor. The chip-enable circuitry is implemented with minimal delay times to compensate for added system decoding.

**Write Cycle:** The complement of the information at the data input is written into the selected location when both the chip-enable input and the read/write input are low. While the read/write input is low, the outputs are in the high-impedance state. When a number of the DM74S289

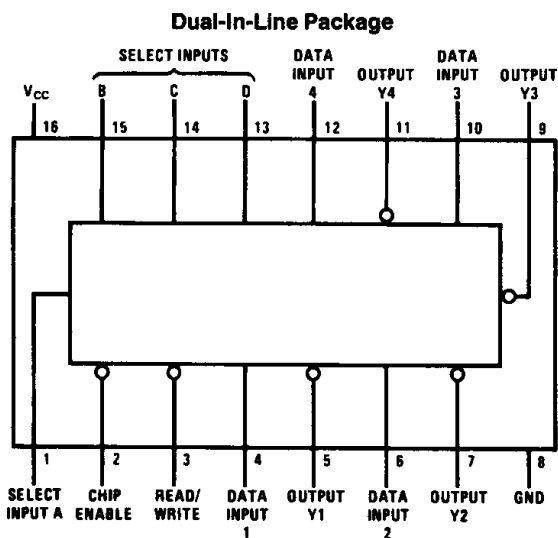
outputs are bus connected, this high-impedance state will neither load nor drive the bus line, but it will allow the bus line to be driven by another active output or a passive pull-up if desired.

**Read Cycle:** The stored information (complement of information applied at the data inputs during the write cycle) is available at the outputs when the read/write input is high and the chip-enable is low. When the chip-enable is high, the outputs will be in the high-impedance state.

### Features

- Commercial address access time 25 ns
- Features open-collector output
- Compatible with most TTL circuits
- Chip-enable input simplifies system decoding

### Connection Diagram



Top View

Order Number DM74S289J or DM74S289N  
See NS Package Number J16A or N16E

### Truth Table

Function	Inputs		Output
	Chip-Enable	Read/Write	
Write (Store Complement of Data)	L	L	High-Impedance
Read	L	H	Stored Data
Inhibit	H	X	High-Impedance

H = High Level, L = Low Level, X = Don't Care

**Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage, $V_{CC}$	7.0V
Input Voltage	5.5V
Output Voltage	5.5V
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering 10 Sec.)	+300°C

**Operating Conditions**

	Min	Max	Units
Supply Voltage ( $V_{CC}$ )			
DM74S289	4.75	5.25	V
Temperature ( $T_A$ )			
DM74S289	0	+70	°C

**DM74S289 Electrical Characteristics**

Over recommended operating free-air temperature range unless otherwise noted (Notes 2 and 3)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$V_{IH}$	High Level Input Voltage		2			V
$V_{IL}$	Low Level Input Voltage				0.8	V
$V_{OH}$	High Level Output Voltage	$V_{CC} = \text{Min}$	2.4	3.2		V
$I_{CEX}$	High Level Output Current	$V_{CC} = \text{Min}$			40	$\mu\text{A}$
					100	
$V_{OL}$	Low Level Output Voltage	$V_{CC} = \text{Min}, I_{OL} = 16 \text{ mA}$			0.45	V
$I_{IH}$	High Level Input Current	$V_{CC} = \text{Max}, V_I = 2.7\text{V}$			25	$\mu\text{A}$
$I_I$	High Level Input Current at Maximum Voltage	$V_{CC} = \text{Max}, V_I = 5.5\text{V}$			1.0	mA
$I_{IL}$	Low Level Input Current	$V_{CC} = \text{Max}, V_I = 0.45\text{V}$			-250	$\mu\text{A}$
$I_{CC}$	Supply Current (Note 4)	$V_{CC} = \text{Max}$		75	110	mA
$V_{IC}$	Input Clamp Voltage	$V_{CC} = \text{Min}, I_I = -18 \text{ mA}$			-1.2	V
$C_{IN}$	Input Capacitance	$V_{CC} = 5\text{V}, V_{IN} = 2\text{V}, T_A = 25^\circ\text{C}, 1 \text{ MHz}$		4.0		pF
$C_O$	Output Capacitance	$V_{CC} = 5\text{V}, V_O = 2\text{V}, T_A = 25^\circ\text{C}, 1 \text{ MHz}, \text{Output "Off"}$		6.0		pF

**DM74S289 Switching Characteristics**

Over recommended operating ranges of  $T_A$  and  $V_{CC}$  unless otherwise noted

Symbol	Parameter	Conditions	DM74S289			Units	
			Min	Typ (Note 2)	Max		
$t_{AA}$	Access Time from Address	$C_L = 30 \text{ pF}, R_{L1} = 300\Omega, R_{L2} = 600\Omega$ (Figure 4)		25	35	ns	
$t_{CHL}$	Enable Time from Chip-Enable			12	17	ns	
$t_{WHL}$	Enable Time from Read/Write		Sense Recovery Time from Read/Write		12	25	ns
$t_{CLH}$	Disable Time from Chip-Enable				12	20	ns
$t_{WLH}$	Disable Time from Read/Write				13	25	ns
$t_{WP}$	Width of Enable Pulse (Read/Write Low)			25			ns
$t_{ASW}$	Setup Time (Figure 2)		Address to Read/Write	0			ns
$t_{DSW}$		Data to Read/Write	25			ns	
$t_{CSW}$		Chip-Enable to Read/Write	0			ns	
$t_{AHW}$	Hold Time (Figure 2)	Address from Read/Write	0			ns	
$t_{DHW}$		Data from Read/Write	0			ns	
$t_{CHW}$		Chip-Enable from Read/Write	0			ns	

**Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

**Note 2:** Unless otherwise specified min/max limits apply across the -55°C to +125°C temperature range for the DM54S189 and across the 0°C to -70°C range for the DM74S189/289. All typicals are given for  $V_{CC} = 5.0\text{V}$  and  $T_A = 25^\circ\text{C}$ .

**Note 3:** All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

**Note 4:**  $I_{CC}$  is measured with all inputs grounded, and the outputs open.

## DM74S289 Switching Time Waveforms

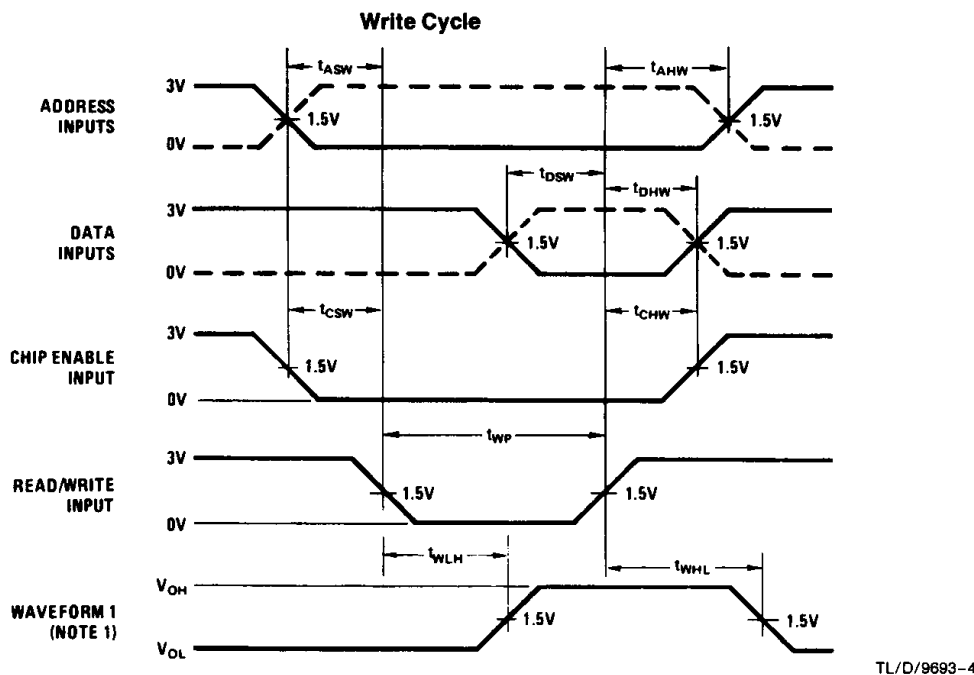
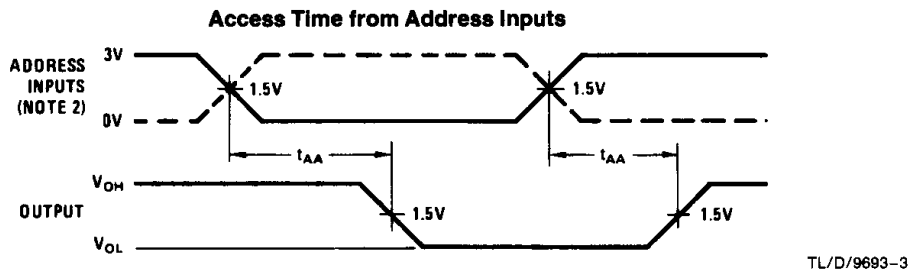
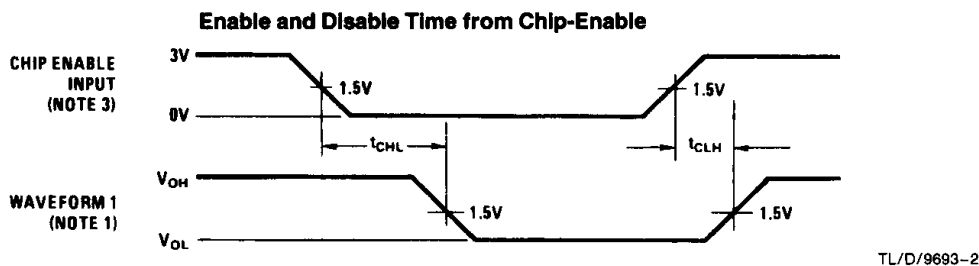


FIGURE 2

**Note 1:** Waveform 1 is for the output with internal conditions such that the output is low except when disabled.

**Note 2:** When measuring delay times from address inputs, the chip-enable is low and the read/write input is high.

**Note 3:** When measuring delay times from chip-enable input, the address inputs are steady-state and the read/write input is high.

**Note 4:** Input waveforms are supplied by pulse generators having the following characteristics  $t_r \leq 2.5$  ns,  $t_f \leq 2.5$  ns,  $PRR \leq 1$  MHz and  $Z_{OUT} = 50\Omega$ .

**Block Diagram**

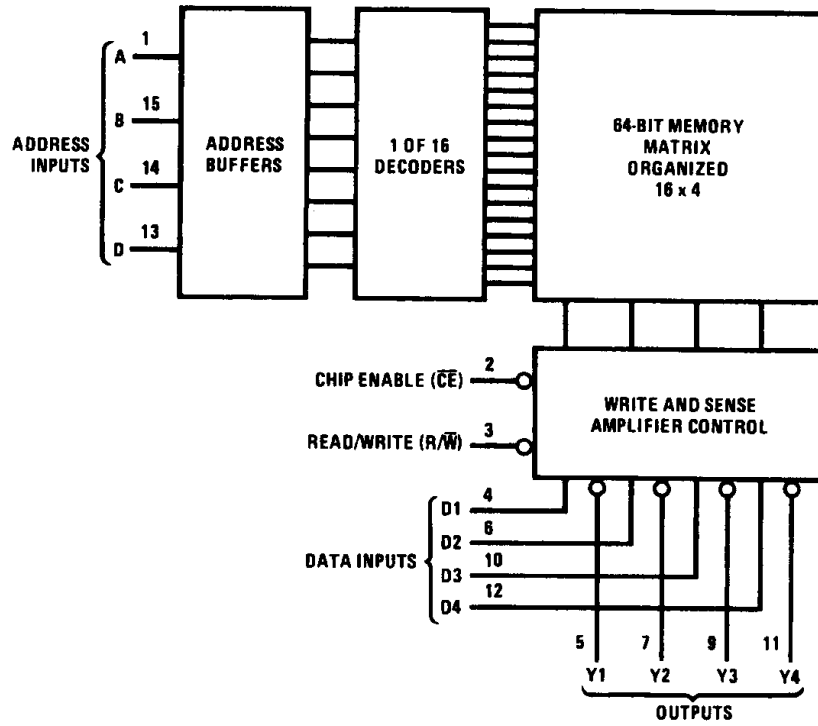
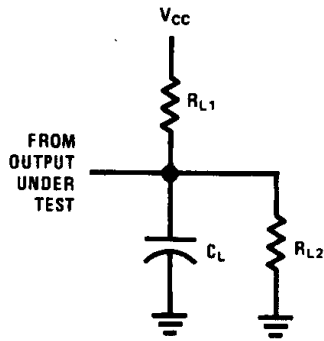


FIGURE 3

TL/D/9693-5

**AC Test Circuit**



TL/D/9693-6